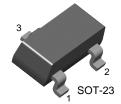


## **KST2907A**

## **General Purpose Transistor**



## 1. Base 2. Emitter 3. Collector

## **PNP Epitaxial Silicon Transistor**

## **Absolute Maximum Ratings** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	-60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-60	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current	-600	mA
P <sub>C</sub>	Collector Power Dissipation	350	mW
T <sub>STG</sub>	Storage Temperature	150	°C

## **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_{C}$ = -10 $\mu$ A, $I_{E}$ =0	-60		V
BV <sub>CEO</sub>	* Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -10mA, I <sub>B</sub> =0	-60		V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = -10μA, I <sub>C</sub> =0	-5		V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = -50V, I <sub>E</sub> =0		-0.01	μΑ
h <sub>FE</sub>	DC Current Gain	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		300	
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	I <sub>C</sub> = -150mA, I <sub>B</sub> = -15mA I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA		-0.4 -1.6	V V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	, , ,		-1.3 -2.6	V V
f <sub>T</sub>	Current Gain Bandwidth Product	I <sub>C</sub> = -50mA, V <sub>CE</sub> = -20V 200 f=100MHz			MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10V, I <sub>E</sub> =0, f=1.0MHz 8		8	pF
t <sub>ON</sub>	Turn On Time	V <sub>CC</sub> = -30V, I <sub>C</sub> = -150mA 50 I <sub>B1</sub> = -15mA		50	ns
t <sub>OFF</sub>	Turn Off Time	$V_{CC}$ = -6V, $I_{C}$ = -150mA 110 $I_{B1}$ = $I_{B2}$ = -15mA		ns	

<sup>\*</sup> Pulse Test: PW≤300μs, Duty Cycle≤2%



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# **Typical Characteristics**

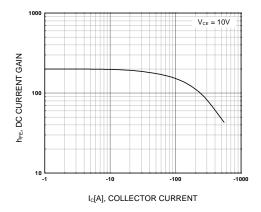


Figure 1. DC current Gain

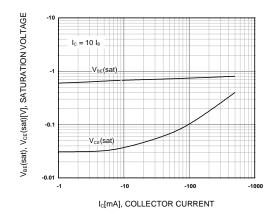


Figure 2. Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage

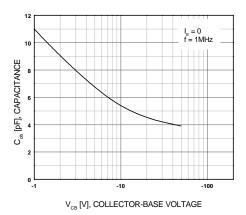


Figure 3. Output Capacitance

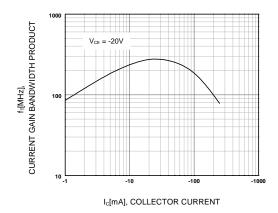
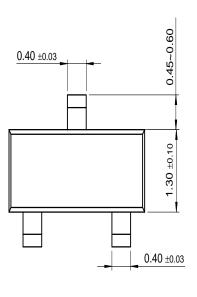
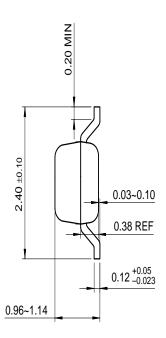


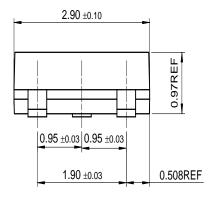
Figure 4. Current Gain Bandwidth Product

# **Package Dimensions**

# **SOT-23**







Dimensions in Millimeters

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E <sup>2</sup> CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	$I^2C^{TM}$	$OCX^{TM}$	RapidConfigure™	UHC™
Across the board.	Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
The Power Franchise™		OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	VCX <sup>TM</sup>
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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